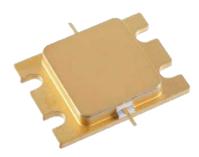


### Features

- High Output Power: P<sub>sat</sub>=48.0dBm (Typ.)
- High Gain: G<sub>p</sub>=11.0dB (Typ.)
- High Power Added Efficiency: PAE=40% (Typ.)
- Frequency Band: 9.3 to 9.5GHz
- Impedance Matched Zin/Zout = 50ohm
- Hermetically Sealed Package

## Description

The SGC9395-50A-R is a high power GaN-HEMT that is internally matched for X-band radar bands to provide optimum power and gain in a 50ohm system.



### ABSOLUTE MAXIMUM RATING (Case Temperature T<sub>c</sub>=25 deg.C)

Item	Symbol	Rating	Unit
Drain-Source Voltage	V <sub>DS</sub>	55	V
Gate-Source Voltage	V <sub>GS</sub>	-15	V
Storage Temperature	T <sub>stg</sub>	-55 to +125	deg.C
Channel Temperature	T <sub>ch</sub>	+250	deg.C

### **RECOMMENDED OPERATING CONDITION**

Item	Symbol	Condition	Limit	Unit
Drain-Source Voltage	V <sub>DS</sub>		<=50	V
Forward Gate Current	$I_{GF}$	Rg=100ohm	<=4	mA
Reverse Gate Current	I <sub>GR</sub>	Rg=100ohm	>=-2.2	mA
Channel Temperature	T <sub>ch</sub>		<+200	deg.C

### ELECTRICAL CHARACTERISTICS (Case Temperature T<sub>c</sub>=25 deg.C)

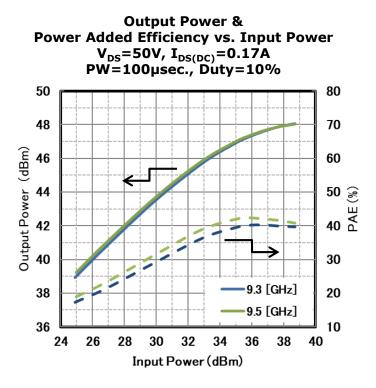
Item	Symbol	Condition		Limit		
			Min.	Тур.	Max.	Unit
Pinch-off Voltage	VP	V <sub>DS</sub> =50V, I <sub>DS</sub> =3mA	-	-4.5	-	V
Frequency Range	Freq.	$V_{DS}$ =50V-typ. $I_{DS(DC)}$ =0.17A-typ. Pulse Width=100µsec. Duty=10%	9.3	-	9.5	GHz
Output Power at Pin=38dBm	P <sub>sat</sub>		47.0	48.0	-	dBm
Power Gain at Pout=47dBm	G <sub>P</sub>		10.0	11.0	-	dB
Drain Current at Pin=38dBm	I <sub>DSR</sub>		-	2.8	4.1	A
Power Added Efficiency at Pin=38dBm	PAE		-	40	-	%
Gain Flatness	ΔG		-	1.6	-	dB
Thermal Resistance	R <sub>th</sub>	Channel to Case (P <sub>diss</sub> =50W, CW)	-	2.4	3.0	deg.C/W

CASE STYLE	IK	
RoHS Compliance	YES	
ESD	Class 2	2000V to <4000V

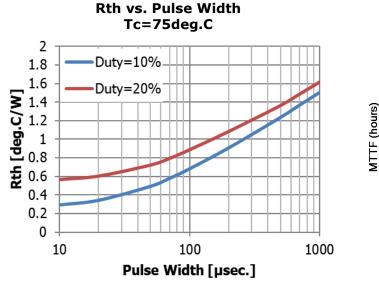
Note: Based on ANSI/ESDA/JEDEC JS-001-2012(C=100pF, R=1.5kohm)



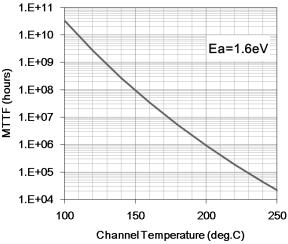
## • **RF** Characteristics



• Thermal Characteristics In Pulsed Operation



MTTF vs. Tch

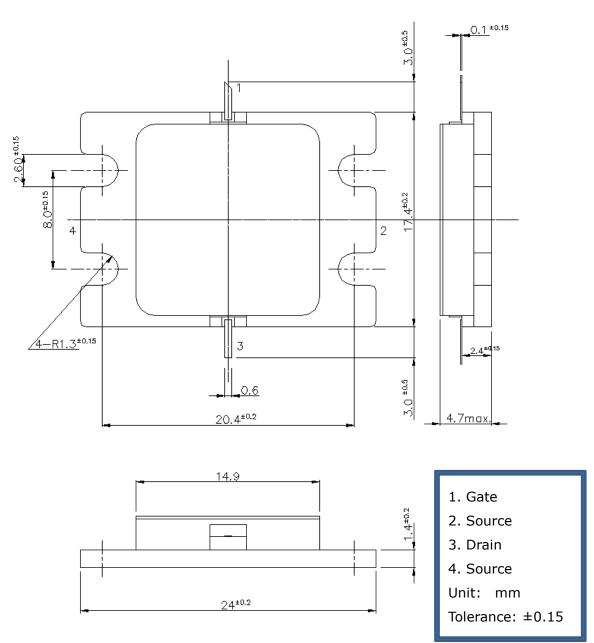




# SGC9395-50A-R X-band Internally Matched GaN-HEMT

## • Package Outline

# Case Style : IK





## For Safety, Observe the Following Procedures Environmental Management

- Do not put this product into the mouth.
- Do not alter the form of this product into a gas, powder, or liquid through burning, crushing, or chemical processing as these by-products are dangerous to the human body if inhaled, ingested, or swallowed.
- Respect all applicable laws of the country when discarding this product. This product must be disposed in accordance with methods specified by applicable hazardous waste procedures.

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